



IXDN602SIATR Information



For Reference Only

Part Number IXDN602SIATR

Manufacturer IXYS Integrated Circuits Division

Category Integrated Circuits (ICs)

PMIC - Gate Drivers

Description 2A 8 LEAD SOIC DUAL NON INVERTIN

Package 8-SOIC (0.154", 3.90mm Width)

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



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IXDN602SIATR Specifications

Manufacturer Part Number IXDN602SIATR Manufacturer IXYS Integrated Circuits Division Category Integrated Circuits (ICs) PMIC - Gate Drivers Package 8-SOIC (0.154", 3.90mm Width) Series - Driven Configuration Low-Side Channel Type Independent Number of Drivers 2 Gate Type IGBT, N-Channel, P-Channel MOSFET Voltage - Supply 4.5 V ~ 35 V Logic Voltage - VIL, VIH 0.8V, 3V Current - Peak Output (Source, Sink) 2A, 2A Input Type Non-Inverting High Side Voltage - Max (Bootstrap) - Rise / Fall Time (Typ) 7.5ns, 6.5ns Operating Temperature -55°C ~ 150°C (TJ) Mounting Type Surface Mount Package / Case 8-SOIC (0.154", 3.90mm Width) Supplier Device Package 8-SOIC			
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Supplier Device Package 8-SOIC	Mounting Type	Surface Mount	
	Package / Case	8-SOIC (0.154", 3.90mm Width)	
Report errors?	Supplier Device Package	8-SOIC	
1		Repor	t errors?

IXDN602SIATR Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

IXDN602SIATR Payment Methods



















IXDN602SIATR Shipping Methods













If you have any question about IXDN602SIATR, please do not hesitate to contact us!

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